Professor Noam Eliaz is the founder of the Department of Materials Science and Engineering at Tel Aviv University (TAU). He is currently the founding Director of TAU’s 3D Printing Research & Development Center. He received his B.Sc. and Ph.D. (direct track) in Materials Engineering as well as M.B.A., all from Ben-Gurion University. He served for three years in the Department of Materials and Failure Analysis of the Israel Air Force. He has published about 400 research publications, including three edited books. He has garnered numerous awards, including the Fulbright and Rothschild postdoctoral scholarships (1989-2001), T.P. Hoar Award for the best paper published in Corrosion Science (2001), JSPS fellowship (Japan, 2005–7), NACE International’s H. H. Uhlig Award (2010), Fellow Award (2012), and Technical Achievements Award (2014), and Northwestern University’s Eshoach scholarship (2013). In 2016 he was elected as the Young Academy. Noam is an 8th generation Israeli. In January 2017 he was appointed by Israel’s Minister of Science, Technology, and Space as a member of the Governing Board of The German-Israeli Foundation for Scientific Research and Development (GIF). In March 2017 he was appointed by the President of The Israel Academy of Sciences and Humanities as a member of the follow-up committee of the “State of Science in Israel.” Noam is married to Billie and the proud father of Orfi, Shahaf, and Shalev.

**Directed Energy Deposition (DED) and the New Tel Aviv University 3D Printing Research and Development Center**

The AM market of metals is rapidly growing. There are several AM processes that are used to manufacture metal parts, the two most common ones are powder bed fusion (PBF) and directed energy deposition (DED). PBF allows printing more complex geometries with finer features and surface roughness compared to DED. In contrast, DED allows for a larger materials range, denser and stronger printed materials; printing of multimechanical (ceramics, composites, and functionally graded materials, FGMs) in the same machine; printing either full parts or local features, coatings, or repairs; faster wall build speeds; larger build volumes; printing on non-horizontal surfaces; use of larger powder sizes for DED with laser compared to PBF with laser; printing in zero-gravity environment (in the case of processes that utilize wire-feed, electron beam, and vacuum environment). Due to the low heat input, with small melt pool and high travel speeds, the deposits cool very fast (typically, 1,000–5,000 °C/s). This generates very fine grain structures that may be one order of magnitude smaller than comparable wrought products. Therefore, the mechanical properties and the quality of the deposits are typically better than castings and approach properties of wrought products. Thus, PBF and DED can be regarded as complementing technologies, rather than competing technologies. Tel Aviv University is currently founding a new 3D Printing Research and Development Center, which will operate the first DED machine in Israel, which is also the first hybrid system in Israel. Collaboration is welcome with academia, industry, and defense organizations. The Laser Engineered Net Shaping (LENS™) process of Optomec (Albuquerque, NM) will be the nucleus of the new center. More specifically, the LENS™ 3D Hybrid 20 Controlled Atmosphere System, with full 5-axis CNC machining and printing capability, 2 KW fiber laser, a glove box with argon atmosphere and an integrated gas purification system that maintains oxygen and moisture levels to below 10 ppm, 4 powder feeders, thermal imager, and melt pool sensor, will be installed.

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Ilan Goldfarb is a Full Professor and Head of the Department of Materials Science and Engineering at Tel Aviv University. After obtaining his doctorate in growth and transmission electron microscopy of thin multilayered films with Prof. Danny Shechtman at Technion’s Department of Materials Engineering in 1994, he was granted a British Council Post-Doctoral Award joined the Department of Materials at Oxford University (UK), where he spent five years as a Research Fellow specializing in surface science, epitaxial growth, and scanning tunneling microscopy. He joined Tel Aviv University in 1999, and spent his 2010-2011 sabatical year at the Nanoelectronics Research Group at Hewlett-Packard Laboratories in Palo Alto (CA, USA) exploring electronic structure and conduction mechanisms in amorphous materials. Until recently, he has headed the TAU Wolfson Applied Materials Research Centre, and served on the Editorial Board of Applied Physics A. Prof. Goldfarb’s current research focuses on self-organization of magnetic epitaxial nanostructures by scanning tunneling microscopy, electron diffraction and photoemission methods, and on electronic structure of amorphous oxide films.

**Nanomagnetic Size Effects in Non-Magnetic Materials**

In this work, I shall survey our work on magnetic properties of epitaxial binary silicide nanostructures. While silicides possess a lot of properties useful for VLSI technology, they are not normally associated with magnetism and magnetic applications. Binary transition-metal silicides usually lack ferromagnetic order in the bulk-size crystals. Silicides of rare-earth metals, are weak ferromagnets or anti-ferromagnets at RT. Yet both groups tend to exhibit increased magnetic ordering in low-dimensional nanostructures, in particular at low temperatures. The origin of this surprising phenomenon is speculated to originate at undercoordinated atoms at the nanostructure boundaries, which may have 2D (surfaces/interfaces), 10 (edges) and 0D (corners) character, with our results pointing mostly to the nanostructure perimeters. Uncompensated spins of the nanostructure edge atoms align into a superspin, such that geometric shape anisotropy of the nanostructures in the array affects the resulting magnetic anisotropy stronger than the magnetocrystalline term, stabilizing ferromagnetic order against thermal excitation. Thus, in principle, magnetic response of nanostructure arrays can be controlled by manipulating size and shape of the nanostructures, providing a plausible route towards design of Si-based bit patterned magnetic recording media and spin injectors.